



<b>APPLICANT'S ART CITATION</b> (Use several sheets if necessary)	Application <b>09/292,186</b>	OFGS File No. <b>IR-1609 (2-1941)</b>
	Applicant <b>Daniel M. Kinzer</b>	
	Filing Date <b>April 15, 1999</b>	Group Art Unit

**U.S. PATENT DOCUMENTS**

Examiner Initial	Document Number							Date	Name	Class	Sub-class	Filing Date If Appropriate
<i>SA</i>	4	9	6	1	1	0	0	10/2/90	Baliga et al.	H01L		
<i>SA</i>	4	5	6	8	9	5	8	2/4/96	Baliga et al.	H01L		
<i>SA</i>	4	8	5	9	6	2	1	8/22/89	Eindhoven	H01L		

**FOREIGN PATENT DOCUMENTS**

	Document Number							Date	Country	Class	Sub-class	Translation	
												Yes	No
<i>SA</i>	2	0	7	7	4	9	5	12/16/81	Great Britain	<i>SA</i>		X	
<i>SA</i>	9	6	3	8	8	6	2	12/5/96	PCT	<i>SA</i>		X	
<i>SA</i>	9	6	3	0	9	4	7	10/3/96	PCT	<i>SA</i>		X	
<i>SA</i>	9	4	1	3	0	1	7	6/9/94	PCT	<i>SA</i>		X	

**OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)**


Examiner

*Shounaugh*

Date Considered

*6/2/00*

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.



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OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)						
SAL		A HIGH-DENSITY ULTRA-LOW Rdson 30 VOLT N-CHANNEL TRENCH FETs FOR DC/DC CONVERTER APPLICATIONS, EL SEGUNDO CA, PAGES 1-4, SODHI R; MALIK R; ASSELANIS D; and KINZER D, "PROCEEDINGS OF INTERNATIONAL SYMPOSIUM OF POWER SEMICONDUCTOR DEVICES AND ICs (ISPSD)", MAY 26, 1999. IEEE CATALOG #99CH36312, PP 303-306				
SAL		ULTRA-LOW Rdson 12 v P-CHANNEL TRENCH MOSFET, EL SEGUNDO CA, PAGES 1-4, KINZER D; ASSELANIS D; and CARTA R, "PROCEEDINGS OF INTERNATIONAL SYMPOSIUM OF POWER SEMICONDUCTOR DEVICES AND ICs (ISPSD)", MAY 26, 1999. IEEE CATALOG #99CH36312, PP 307-310				
SAL		INTEGRATED DESIGN ENVIRONMENT FOR DC/DC CONVERTER FET OPTIMIZATION, EL SEGUNDO CA, PAGES 1-4, SODHI R; BROWH S Sr.; and KINZER D.; DALLAS TX, MARTINEZ R; STANFORD CA, WIEMER M, "PROCEEDINGS OF INTERNATIONAL SYMPOSIUM OF POWER SEMICONDUCTOR DEVICES AND ICs (ISPSD)", MAY 26, 1999. IEEE CATALOG #99CH36312, PP 241-244				
Examiner	Shousraff		Date Considered	6/2/00		
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